74AUP2G240

Low-power dual inverting buffer/line driver; 3-state Rev. 9 — 19 March 2019 Product data sheet

1. General description

The 74AUP2G240 provides the dual inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input (nOE). A HIGH level at pin nOE causes the output to assume a high-impedance OFF-state.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This device has the input-disable feature, which allows floating input signals. The inputs are disabled when the output enable input $n\overline{OE}$ is HIGH.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- · Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD78 Class II
- Inputs accept voltages up to 3.6 V
- Low-noise overshoot and undershoot < 10 % of V_{CC}
- · Input-disable feature allows floating input conditions
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP2G240DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74AUP2G240GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1
74AUP2G240GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm	SOT1089
74AUP2G240GM	-40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm	SOT902-2
74AUP2G240GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	SOT1116
74AUP2G240GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203

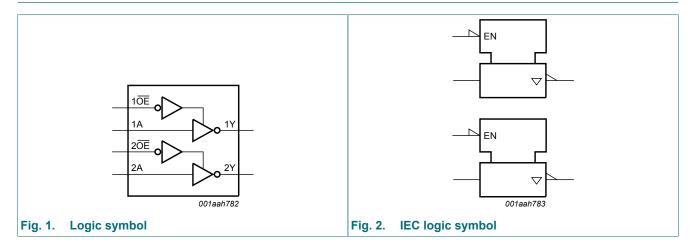
4. Marking

Table 2. Marking codes

Type number	Marking code [1]
74AUP2G240DC	p40
74AUP2G240GT	p40
74AUP2G240GF	p2
74AUP2G240GM	p40
74AUP2G240GN	p2
74AUP2G240GS	p2

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

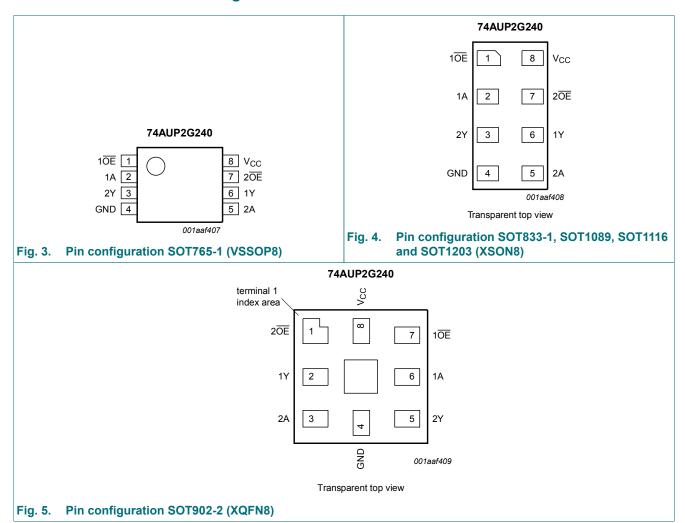
5. Functional diagram



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6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin		Description
	SOT765-1, SOT833-1, SOT1089, SOT1116 and SOT1203	SOT902-2	
1 OE , 2 OE	1, 7	7, 1	output enable input (active LOW)
1A, 2A	2, 5	6, 3	data input
GND	4	4	ground (0 V)
1Y, 2Y	6, 3	2, 5	data output
V _{CC}	8	8	supply voltage

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7. Functional description

Table 4. Function table

 $H = HIGH \text{ voltage level}; L = LOW \text{ voltage level}; X = don't care; Z = high-impedance OFF-state.}$

Input nOE		Output
nŌE	nA	nY
L	L	Н
L	Н	L
Н	X	Z

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 \text{ V to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [2]	-	250	mW

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	0	200	ns/V

^[2] For VSSOP8 packages: above 110 °C the value of P_{tot} derates linearly with 8.0 mW/K. For XSON8 and XQFN8 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

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10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	5 °C						
V _{IH}	HIGH-level input	V _{CC} = 0.8 V	(0.70V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	C	0.65V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V		1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V		2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V		-	-	0.30V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V		-	-	0.35V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V		-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V		-	-	0.9	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}					
	voltage	I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	V	_{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	().75V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V		1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V		1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V		2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V		1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V		2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V		2.6	-	-	V
V _{OL}	LOW-level output	V _I = V _{IH} or V _{IL}					
	voltage	I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V		-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V		-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V		-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V		-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V		-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V		-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V		-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V		-	-	0.44	V
l _l	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V		-	-	±0.1	μA
l _{OZ}	OFF-state output current	V _I = V _{IH} or V _{IL} ; V _O = 0 V to 3.6 V; V _{CC} = 0 V to 3.6 V		-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$		-	-	±0.2	μΑ
Δl _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V		-	-	±0.2	μA
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V		-	-	0.5	μA
ΔI _{CC}	additional supply current	data input; $V_I = V_{CC}$ - 0.6 V; $I_O = 0$ A; $V_{CC} = 3.3$ V	[1]	-	-	40	μΑ
		$\overline{\text{NOE}}$ input; $V_1 = V_{CC} - 0.6 \text{ V}$; $I_0 = 0 \text{ A}$; $V_{CC} = 3.3 \text{ V}$	[1]	-	-	110	μA
		disabled inputs; V _I = GND to 3.6 V; nOE = V _{CC} ; V _{CC} = 0.8 V to 3.6 V		-	-	1	μA

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
C _I	input capacitance	V_{CC} = 0 V to 3.6 V; V_I = GND or V_{CC}		-	0.6	-	pF
Co	output capacitance	output enabled; V _O = GND; V _{CC} = 0 V		-	1.7	-	pF
		output disabled; V_{CC} = 0 V to 3.6 V; V_{O} = GND or V_{CC}		-	1.5	-	pF
T _{amb} = -	40 °C to +85 °C		·	'		<u>'</u>	
V _{IH}	HIGH-level input	V _{CC} = 0.8 V		0.70V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V		0.65V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V		1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V		2.0	-	-	V
V_{IL}	LOW-level input	V _{CC} = 0.8 V		-	-	0.30V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V		-	-	0.35V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V		-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V		-	-	0.9	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}					
	voltage	I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V		V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V		0.7V _{CC}	-	- V - V - V	
		I _O = -1.7 mA; V _{CC} = 1.4 V		1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V		1.30	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V		1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V		1.85	-	-	V
		I_{O} = -2.7 mA; V_{CC} = 3.0 V		2.67	-	-	V
		I_{O} = -4.0 mA; V_{CC} = 3.0 V		2.55	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}					
	voltage	I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V		-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V		-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V		-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V		-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V		-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V		-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V		-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V		-	-	0.45	V
l _l	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V		-	-	±0.5	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$		-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V		-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V		-	-	±0.6	μΑ
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V		-	-	0.9	μA
ΔI _{CC}	additional supply current	data input; $V_I = V_{CC}$ - 0.6 V; $I_O = 0$ A; $V_{CC} = 3.3$ V	[1]	-	-	50	μA
		\overline{OE} input; $V_I = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$; $V_{CC} = 3.3 \text{ V}$	[1]	-	-	120	μΑ
		disabled inputs; V _I = GND to 3.6 V; $\overline{\text{OE}}$ = V _{CC} ; V _{CC} = 0.8 V to 3.6 V		-	-	1	μA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	-40 °C to +125 °C					
V _{IH}	HIGH-level input	V _{CC} = 0.8 V	0.75V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.70V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.25V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.30V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.33V _{CC} \ 0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
lį	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	μA
l _{OZ}	OFF-state output current	V _I = V _{IH} or V _{IL} ; V _O = 0 V to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μA
Δl _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.75	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	1.4	μA
ΔI _{CC}	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$; $V_{CC} = 3.3 \text{ V}$	[1] -	-	75	μA
		$\overline{\text{NOE}}$ input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1] -	-	180	μA
		disabled inputs; V_I = GND to 3.6 V; $n\overline{OE}$ = V_{CC} ; V_{CC} = 0.8 V to 3.6 V	-	-	1	μA

^[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

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11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 8.

Symbol	Parameter	Conditions		25 °C		-40	°C to +1	25 °C	Unit
			Min	Typ [1]	Max	Min	Max (85 °C)	Max (125 °C)	
C _L = 5 p	F					•			
t _{pd}	propagation	nA to nY; see Fig. 6 [2]							
	delay	V _{CC} = 0.8 V	-	22.3	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.0	5.8	12.6	2.8	14.1	15.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.0	7.3	2.1	8.5	9.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.2	5.5	1.9	6.7	7.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	2.6	4.1	1.5	4.8	5.3	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.3	3.6	1.3	4.1	4.6	ns
t _{en}	enable time	nOE to nY; see Fig. 7 [3]							
		V _{CC} = 0.8 V	-	70.2	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.1	6.4	14.3	2.8	15.9	17.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	4.4	8.1	2.2	9.5	10.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	3.6	6.2	1.9	7.4	8.2	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	2.8	4.6	1.7	5.4	6.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.5	4.0	1.7	4.7	5.3	ns
t _{dis}	disable time	nOE to nY; see Fig. 7 [4]							
		V _{CC} = 0.8 V	-	14.8	-	-	-	-	ns ns
		V _{CC} = 1.1 V to 1.3 V	2.0	4.3	7.4	2.3	8.3	9.2	
		V _{CC} = 1.4 V to 1.6 V	1.6	3.2	5.2	1.7	5.9	6.5	ns
		V _{CC} = 1.65 V to 1.95 V	1.5	3.0	4.8	1.5	5.5	6.1	ns
		V _{CC} = 2.3 V to 2.7 V	1.1	2.2	3.5	1.4	4.0	4.5	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	2.5	3.9	1.4	4.5	5.0	ns
C _L = 10	pF								
t _{pd}	propagation	nA to nY; see Fig. 6 [2]							
	delay	V _{CC} = 0.8 V	-	25.7	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.5	6.6	14.5	3.2	16.3	18.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.6	8.4	2.0	9.9	10.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.8	6.4	1.8	7.7	8.6	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.1	4.8	1.7	5.7	6.4	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.8	4.3	1.7	5.0	5.5	ns
t _{en}	enable time	nOE to nY; see Fig. 7 [3]							
		V _{CC} = 0.8 V	-	74.0	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	7.4	16.3	3.2	18.2	20.1	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	5.1	9.2	2.1	10.9	12.0	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	4.1	7.1	1.8	8.5	9.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.4	5.4	1.7	6.4	7.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	3.1	4.8	1.7	5.7	6.3	ns

Symbol	Parameter	Conditions		25 °C		-40	°C to +1	25 °C	Unit
			Min	Typ [1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{dis}	disable time	nOE to nY; see Fig. 7 [4]							
		V _{CC} = 0.8 V	-	33.7	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.4	5.4	9.0	3.2	10.0	11.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	4.1	6.3	2.1	7.1	7.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.2	6.3	1.8	7.1	7.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	3.0	4.6	1.7	5.2	5.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.8	5.7	1.7	6.4	7.1	ns
C _L = 15	pF								
t _{pd}	propagation	nA to nY; see Fig. 6 [2]							
	delay	V _{CC} = 0.8 V	-	29.0	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.9	7.4	16.3	3.6	18.4	20.2	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.1	9.4	2.5	11.1	12.3	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	4.2	7.2	2.1	8.7	9.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.5	5.4	1.9	6.5	7.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.3	4.9	1.9	5.7	6.4	ns
t _{en}	enable time	nOE to nY; see Fig. 7 [3]							
		V _{CC} = 0.8 V	-	77.8	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.0	8.2	18.2	3.6	20.4	22.5	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.6	10.3	2.5	12.2	13.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.6	7.9	2.1	9.5	10.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.9	6.0	2.0	7.2	7.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.6	5.5	1.9	6.4	7.1	ns
t _{dis}	disable time	nOE to nY; see Fig. 7 [4]							
		V _{CC} = 0.8 V	-	62.5	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	6.6	10.4	3.6	11.6	12.8	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.0	7.4	2.5	8.4	9.3	ns
		V _{CC} = 1.65 V to 1.95 V	3.0	5.3	7.8	2.1	8.7	9.7	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.8	5.7	2.0	6.4	7.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.9	5.0	7.4	1.9	8.3	9.1	ns
C _L = 30	pF								
t _{pd}	propagation	nA to nY; see Fig. 6 [2]							
	delay	V _{CC} = 0.8 V	-	39.1	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	5.0	9.7	21.6	4.6	24.3	26.8	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	6.7	12.3	3.0	14.6	16.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.9	5.5	9.5	2.7	11.5	12.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.6	7.1	2.5	8.6	9.5	ns
		V _{CC} = 3.0 V to 3.6 V	2.6	4.3	6.4	2.5	7.7	8.5	ns

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Symbol	Parameter	Conditions		25 °C		-40	°C to +1	25 °C	Unit
			Min	Typ [1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{en}	enable time	nOE to nY; see Fig. 7 [3]							
		V _{CC} = 0.8 V	-	89.4	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	5.2	10.6	23.8	4.6	26.7	29.5	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	7.3	13.2	3.0	15.7	17.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.0	6.0	10.2	2.7	12.3	13.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.8	5.0	7.8	2.6	9.3	10.3	ns
		V _{CC} = 3.0 V to 3.6 V	2.8	4.8	7.1	2.6	8.4	9.3	ns
t _{dis}	disable time	nOE to nY; see Fig. 7 [4]							
		V _{CC} = 0.8 V	-	68.9	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	6.0	9.3	15.0	4.6	16.5	18.2	ns
		V _{CC} = 1.4 V to 1.6 V	4.4	7.7	11.0	3.0	12.2	13.4	ns
		V _{CC} = 1.65 V to 1.95 V	5.1	8.8	12.4	2.7	13.7	15.1	ns
		V _{CC} = 2.3 V to 2.7 V	3.6	6.2	9.0	2.6	10.0	11.0	ns
		V _{CC} = 3.0 V to 3.6 V	5.2	8.8	12.7	2.6	14.0	15.4	ns
C _L = 5 p	F, 10 pF, 15 pF a	nd 30 pF							
C _{PD}	power	$f = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [5]							
	dissipation capacitance	V _{CC} = 0.8 V	-	2.7	-	-	-	-	pF
	Capacitarice	V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.2	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.7	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.2	-	-	-	-	pF

- All typical values are measured at nominal V_{CC}.
- [2] [3]
- [4]
- All typical values are measured at nominal V_{CC} . t_{pd} is the same as t_{PLH} and t_{PPL} . t_{en} is the same as t_{PZH} and t_{PZL} . t_{dis} is the same as t_{PZH} and t_{PLZ} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

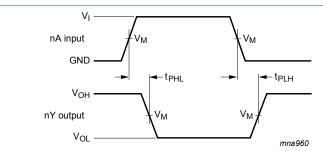
V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

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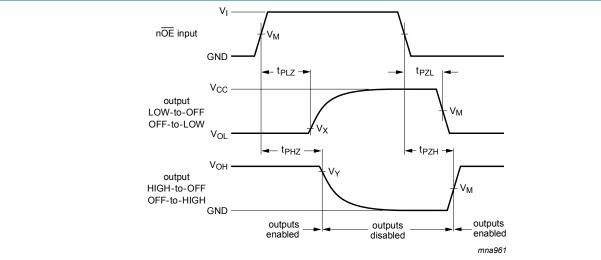
11.1. Waveforms and test circuit



Measurement points are given in <u>Table 9</u>.

 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 6. The data input (nA) to output (nY) propagation delays



Measurement points are given in Table 9.

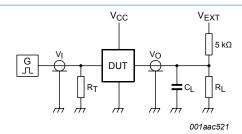
 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 7. 3-state enable and disable times

Table 9. Measurement points

Supply voltage	Input			Output		
V _{CC}	V _M	VI	$t_r = t_f$	V _M	V _X	V _Y
0.8 V to 1.6 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.1 V	V _{OH} - 0.1 V
1.65 V to 2.7 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V
3.0 V to 3.6 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V

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Test data is given in Table 10.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig. 8. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Load		V _{EXT}		
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times R_L = 5 k Ω . For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

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12. Package outline

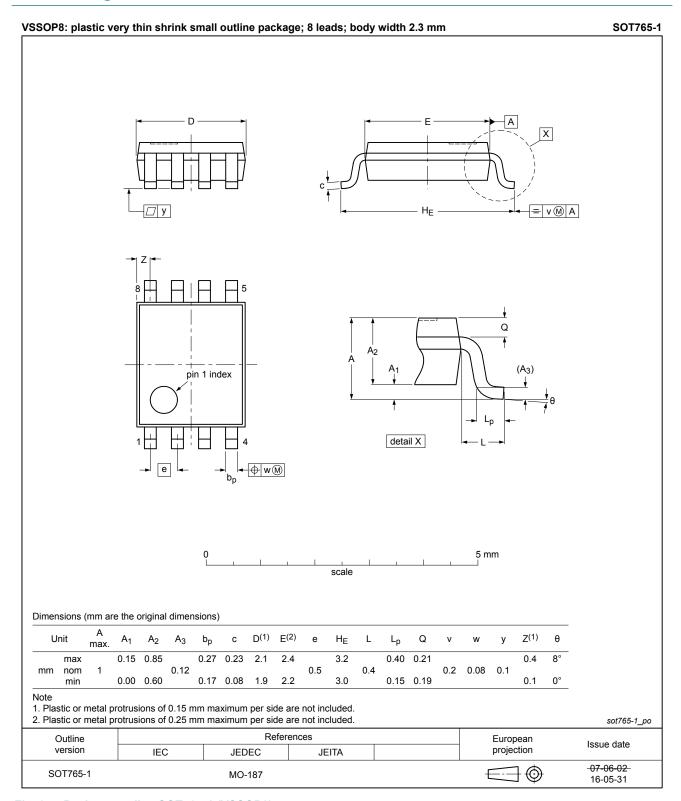


Fig. 9. Package outline SOT765-1 (VSSOP8)

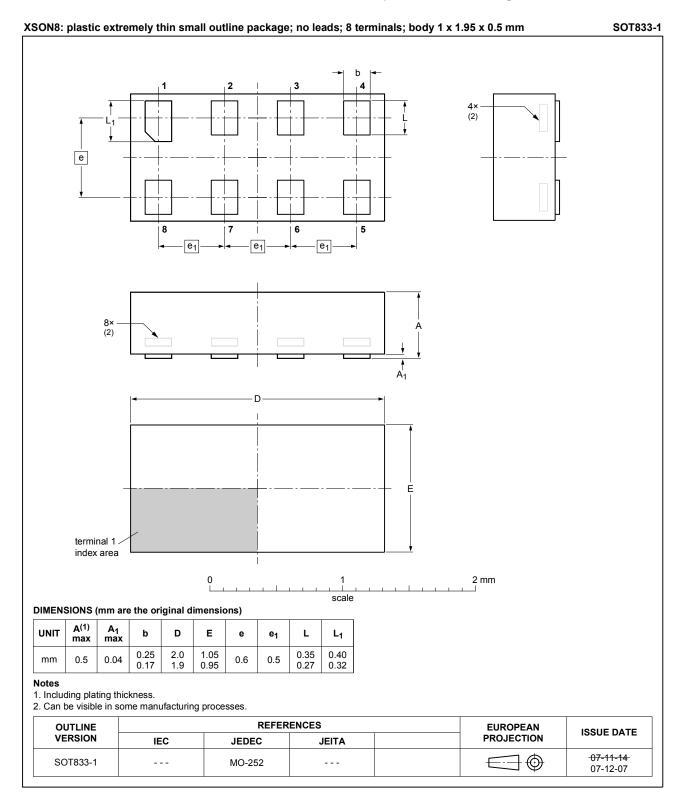


Fig. 10. Package outline SOT833-1 (XSON8)

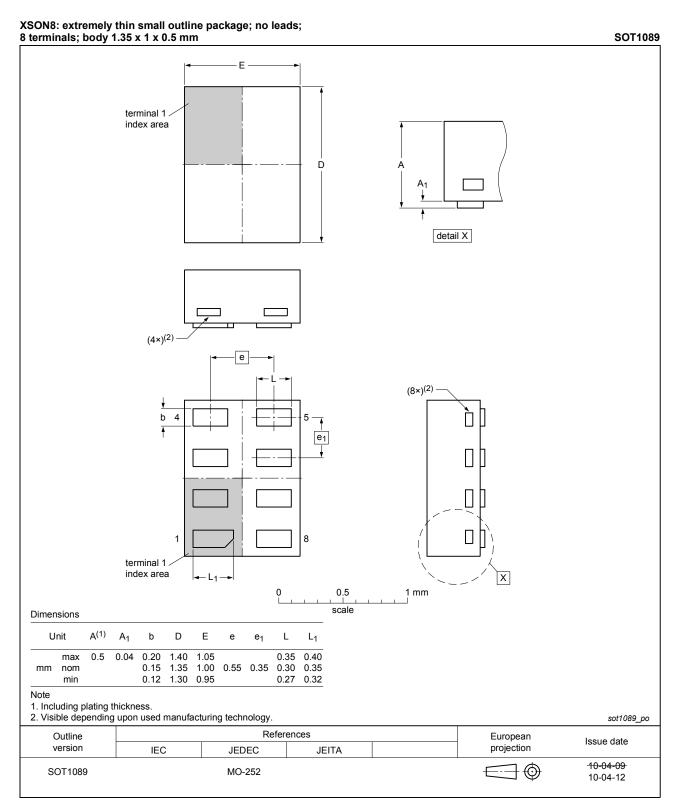


Fig. 11. Package outline SOT1089 (XSON8)

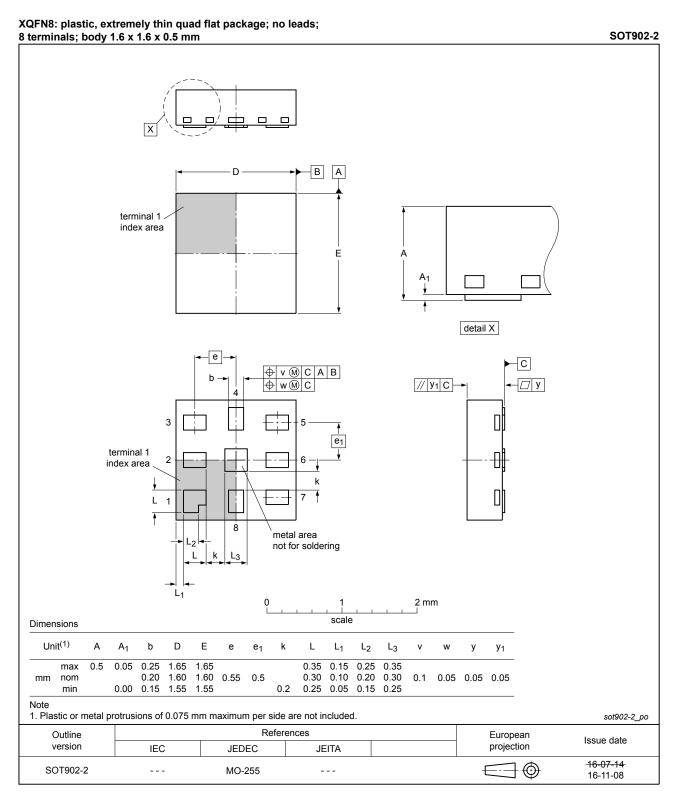


Fig. 12. Package outline SOT902-2 (XQFN8)

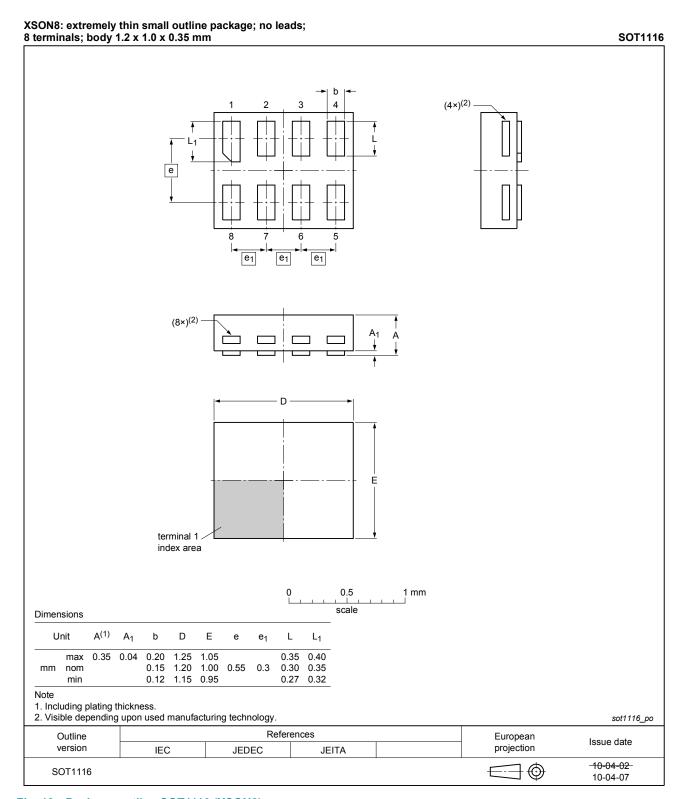


Fig. 13. Package outline SOT1116 (XSON8)

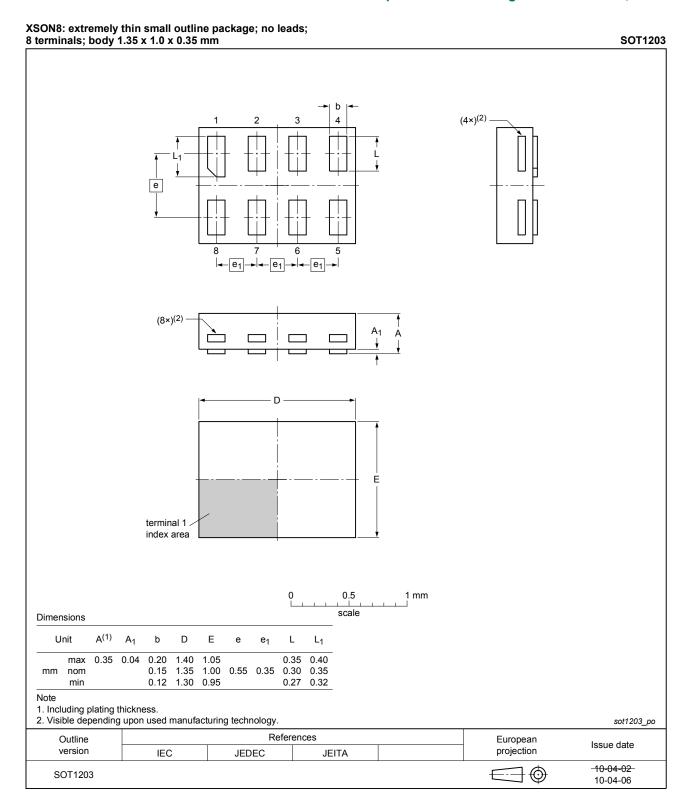


Fig. 14. Package outline SOT1203 (XSON8)

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13. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74AUP2G240 v.9	20190319	Product data sheet	-	74AUP2G240 v.8	
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type number 74AUP2G240GD (SOT996-2) removed. Package outline drawing SOT765-1 (VSSOP8) updated. Package outline drawing SOT902-2 (XQFN8) updated. 				
74AUP2G240 v.8	20130124	Product data sheet	-	74AUP2G240 v.7	
Modifications:	For type number 74AUP2G240GD XSON8U has changed to XSON8.				
74AUP2G240 v.7	20120606	Product data sheet	-	74AUP2G240 v.6	
74AUP2G240 v.6	20111205	Product data sheet	-	74AUP2G240 v.5	
74AUP2G240 v.5	20100913	Product data sheet	-	74AUP2G240 v.4	
74AUP2G240 v.4	20090630	Product data sheet	-	74AUP2G240 v.3	
74AUP2G240 v.3	20090407	Product data sheet	-	74AUP2G240 v.2	
74AUP2G240 v.2	20080222	Product data sheet	-	74AUP2G240 v.1	
74AUP2G240 v.1	20061006	Product data sheet	-	-	

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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